## LECTROSTATIC POTENTIAL AND CAPACITANCE MINDMA # Electric Potential (V) (# Capacitor (Charge Storage Device) · Work done in moving a unit (+ve) C=Q Parallel plate Capacitor charge from infinity to point. Air medium, C= AE · Point Charge, V = Kg · Dielectric completely filled blw plates, Ring C= KAE At center, V= Kq · Dielectric filled up to thickness t and same Along axis, V= Kq area as plates, G= AE. · Electric Dipole d-t[1-1/4 · Series/parallel Vaxial = Kp Combination. Energy Stored $E = Q^2 = \frac{V^2C}{2C}$ Veguitorial = 0) ·Hollow Sphere | Metallic Conductor · RC Circuit $V = \frac{Kq}{R} \left( x \leq R \right)$ 1At t=0, Cas wire. In Charging t=00, Cas open circuit (Initially uncharged capacitor) V= Kg (n > R) # Electrostatics of Conductors:-# Electric Potential Energy (Einside = 0) (Esurgace = 0 (along normal) · Two point charges, U12=Kq192 · Excess charge only on surface. (with sign consider) Vinside = Vsurface · Multiple charges, $(U=U_{12}+U_{13}+U_{23}+...$ · Electrostatic Shielding · Dipole in ext field U=-p. E (E inside uncharged cavity is always o) · Energy Conservation # Potential Difference and Field-# Dielectrics and Polarisation -> (1V=Vf-Vi) · Dielectric: Non conducting substance. (dV=-E.dr) or (E=-dV) · Fox dielectric, Enet, inside #0 Einduced = Fext . Work done in moving charge q, W=qAV) · Polarisation P=XE · Equipotential Surfaces. (dipole moment per unit NEET SLAYER